V_{RRM}	=	200 V
I_{FAVM}	=	11000 A
I_{FRMS}	=	17300 A
I_{FSM}	=	85000 A
V_{F0}	=	0.75 V
r_F	=	0.020 mW

Rectifier Diode

5SDD 0120C0200

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- **Optimized for high current rectifiers**
- **Very low on-state voltage**
- **Very low thermal resistance**

Blocking

V_{RRM}	Repetitive peak reverse voltage	200 V	Half sine wave, t_P = 10 ms, f = 50 Hz
V_{RSM}	Maximum peak reverse voltage	300 V	Half sine wave, t_P = 10 ms
I_{RRM}	Repetitive peak reverse current	≤ 50 mA	T_j = 170 °C $V_R = V_{RRM}$

Mechanical

F_M	Mounting force	min.	35 kN
		max.	40 kN
a	Acceleration: Device unclamped Device clamped		 50 m/s^2 200 m/s^2
m	Weight		0.22 kg
D_S	Surface creepage distance		4 mm
D_a	Air strike distance		4 mm

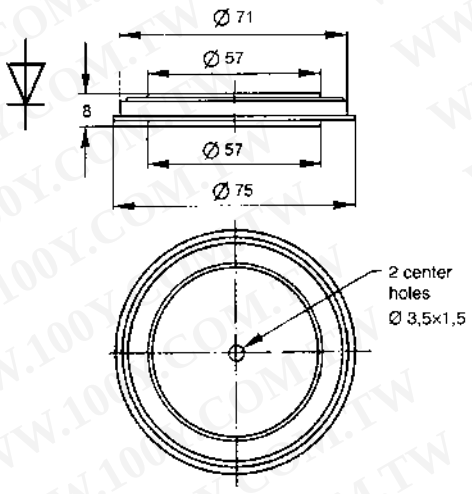


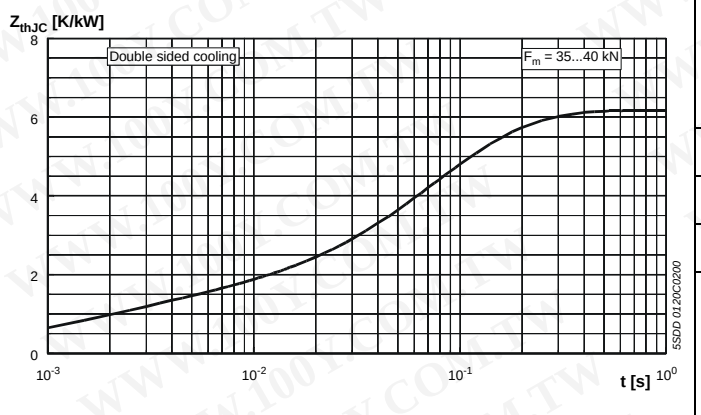
Fig. 1
Outline drawing.
All dimensions are in millimeters and represent nominal values unless stated otherwise.

On-state

I_{FAVM}	Max. average on-state current	11000 A	Half sine wave, T_c = 85 °C	
I_{FRMS}	Max. RMS on-state current	17300 A		
I_{FSM}	Max. peak non-repetitive surge current	85000 A	t_p = 10 ms	Before surge
		92500 A	t_p = 8.3 ms	T_j = 170 °C
$\int I^2dt$	Max. surge current integral	36100 kA^2s	t_p = 10 ms	After surge:
		35700 kA^2s	t_p = 8.3 ms	$V_R \approx 0V$
$V_{F\,max}$	Maximum on-state voltage	≤ 0.92 V	I_F = 8000 A	T_j = 170 °C
V_{F0}	Threshold voltage	0.75 V	Approximation for	T_j = 170 °C
r_F	Slope resistance	0.020 mΩ	I_F = 8 - 18 kA	

Thermal characteristics

T_j	Operating junction temperature range	-40...170 °C		
T_{stg}	Storage temperature range	-40…170 °C		
$R_{th(j-c)}$	Thermal resistance junction to case	≤ 12 K/kW	Anode side cooled	F_M = 35…40 kN
		≤ 12 K/kW	Cathode side cooled	
		≤ 6 K/kW	Double side cooled	
$R_{th(c-h)}$	Thermal resistance case to heatsink	≤ 6 K/kW	Single side cooled	
		≤ 3 K/kW	Double side cooled	



$$Z_{th(j-c)}(t) = \sum_{i=1}^{4} R_i(1 - e^{-t/t_i})$$

i	1	2	3	4
R_i (K/kW)	3.37	1.50	0.63	0.67
τ_i (s)	0.095	0.048	0.0035	0.001

F_M = 35…40 kN
Double side cooled

Fig. 2 Transient thermal impedance (junction-to-case) vs. time in analytical and graphical forms.

On-state characteristics

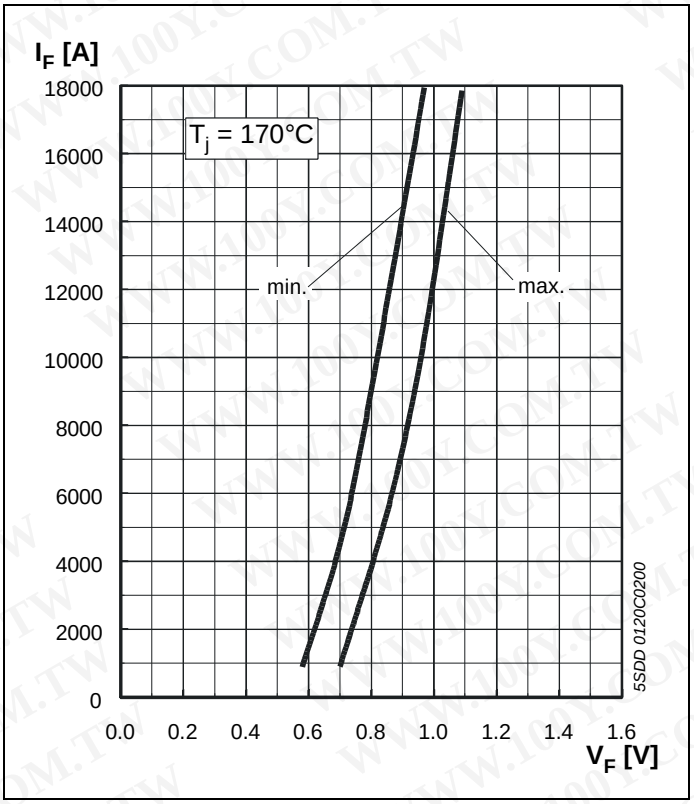


Fig. 3 Forward current vs. forward voltage (min. and max. values).

Surge current characteristics

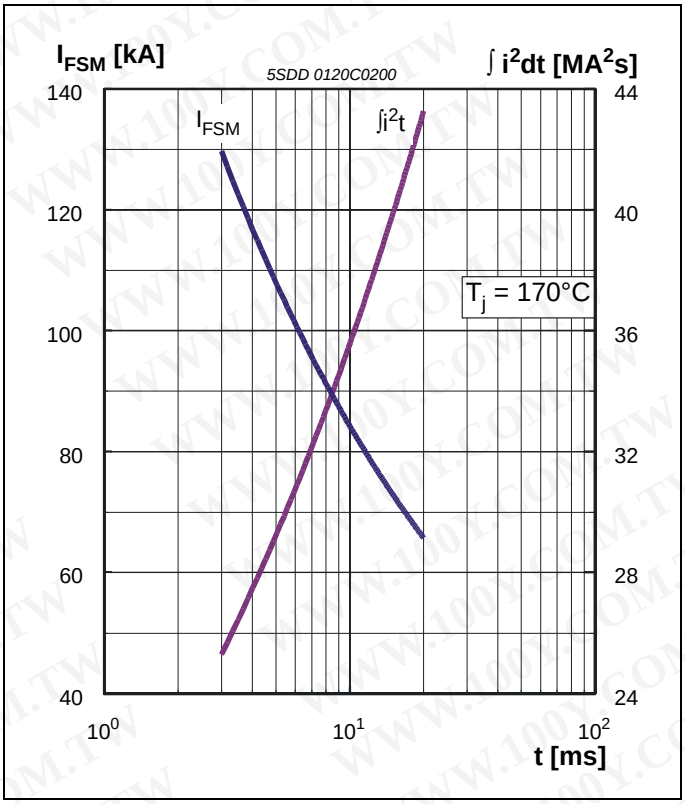


Fig. 4 Surge current and fusing integral vs. pulse width (max. values) for non-repetitive, half-sinusoidal surge current pulses.

Current load capability

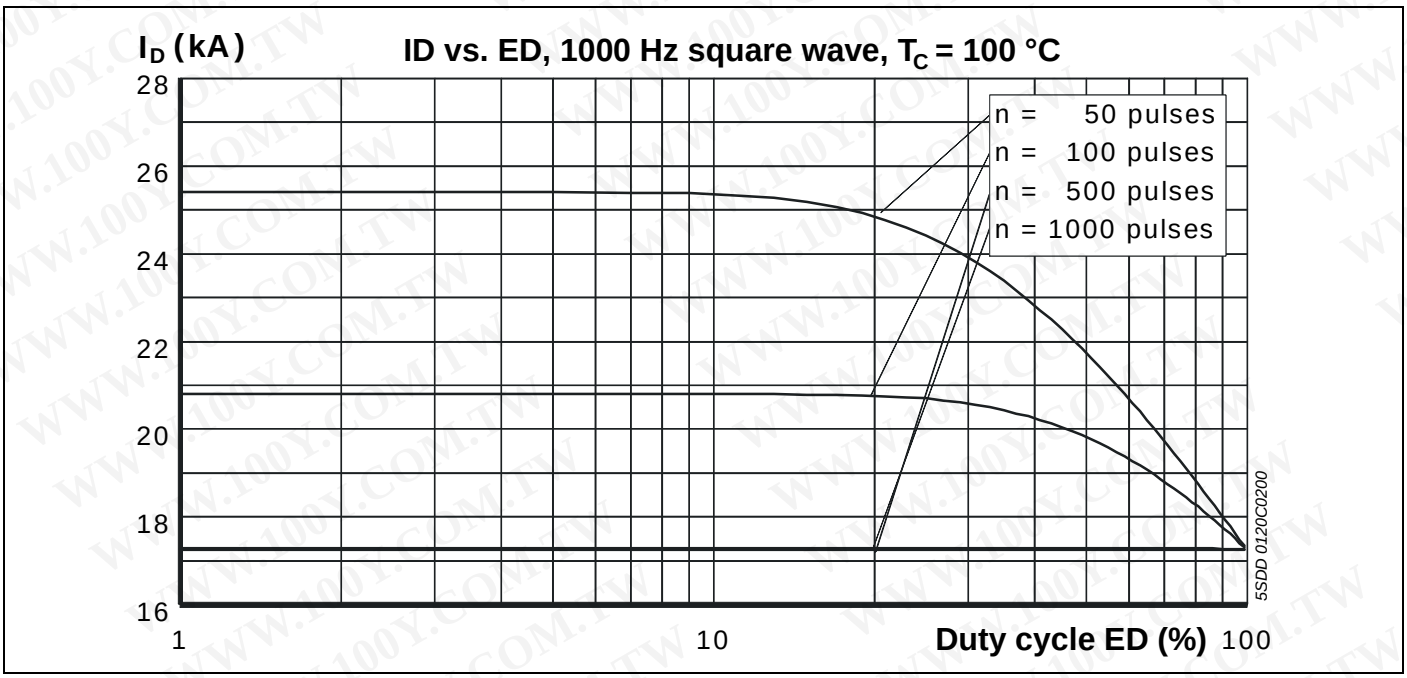


Fig. 5 DC-output current with single-phase centre tap

Current load capacity, cont.

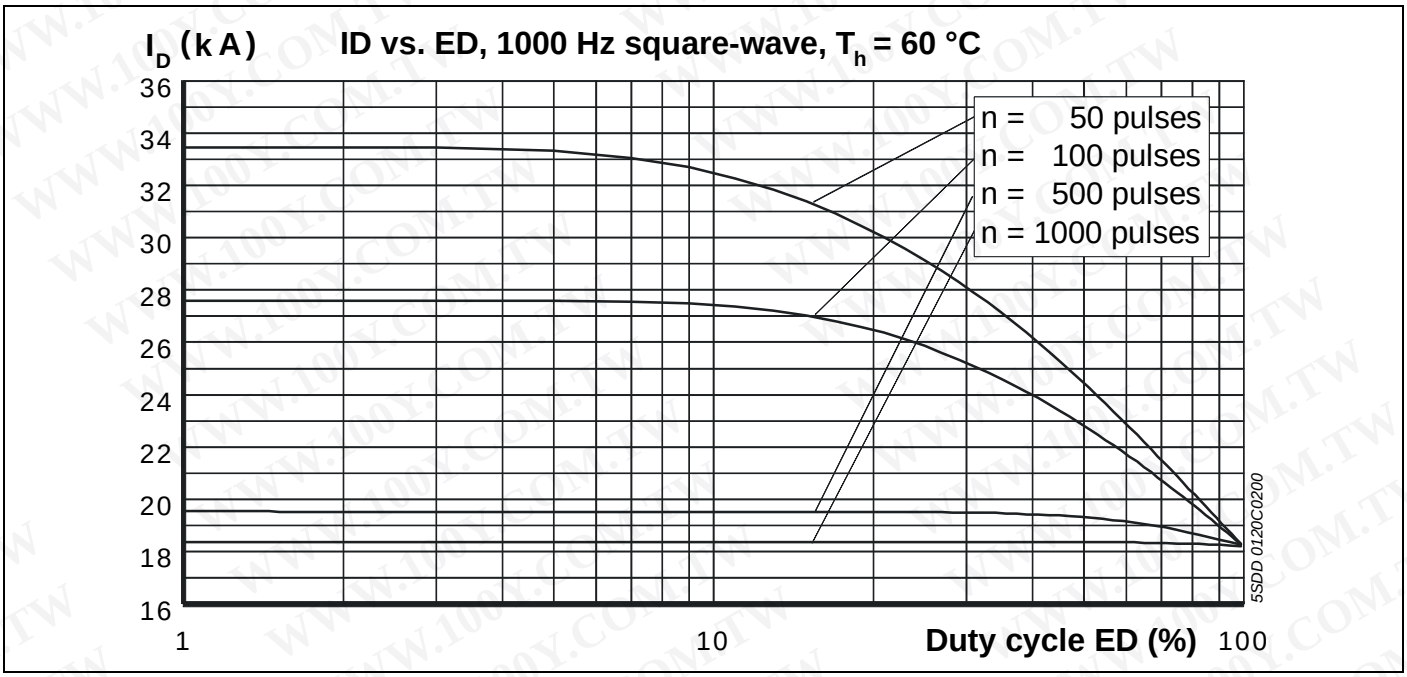


Fig. 6 DC-output current with single-phase centre tap

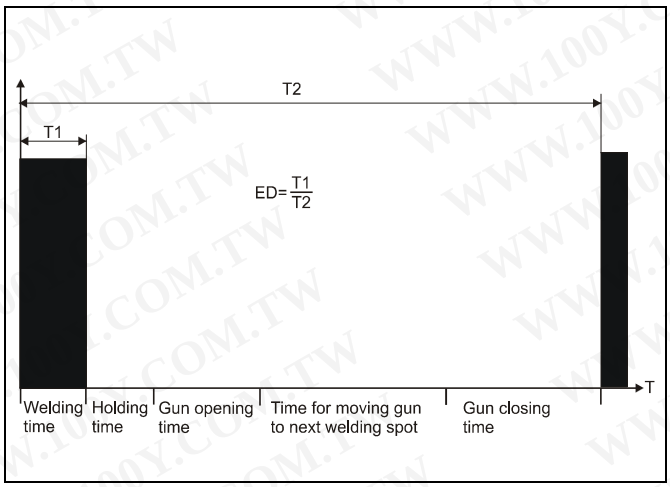


Fig. 7 Definition of ED for typical welding sequence

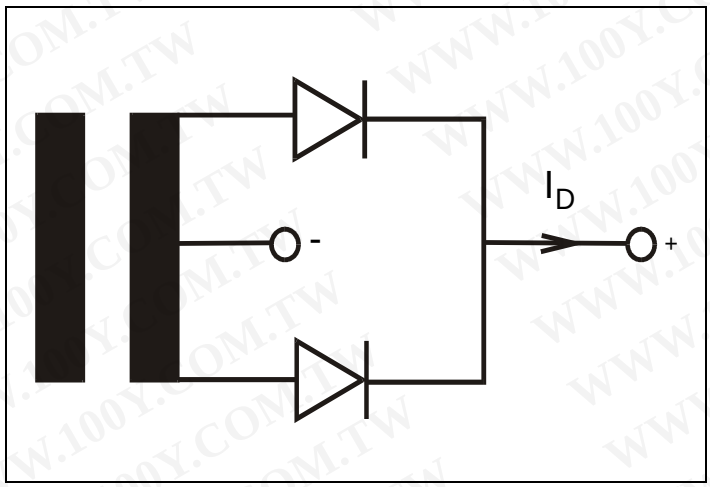


Fig. 8 Definition of ID for single-phase centre tap

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